SHINDENGEN

Bridge Diode

Single In-line Package

D10XB60H

600V 10A

FEATURES

- Thin Single In-Line Package
- High current capacity with Small Package
- High IFSM
- Superior Thermal Conductivity

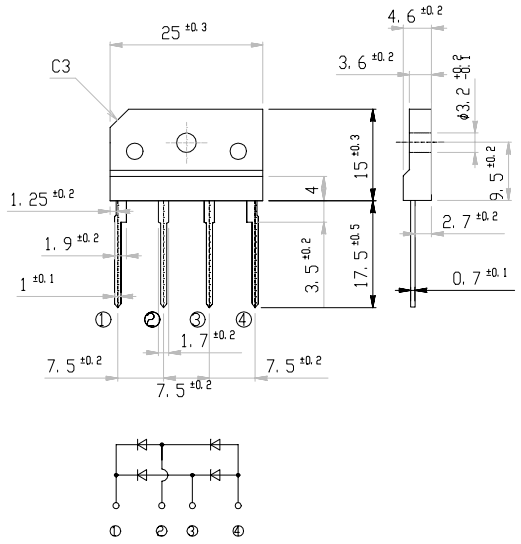
APPLICATION

- Switching power supply
- Home Appliances, Office Equipment
- Factory Automation, Inverter

OUTLINE DIMENSIONS

Case : 3S

Unit : mm



RATINGS

●Absolute Maximum Ratings (If not specified Tc=25℃)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	Tstg		−40～150	℃
Operating Junction Temperature	Tj		150	℃
Maximum Reverse Voltage	V_{RM}		600	V
Average Rectified Forward Current	I_O	50Hz sine wave, R-load With heatsink Tc=112℃	10	A
		50Hz sine wave, R-load Without heatsink Ta=25℃	2.9	
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1cycle peak value, Rating of per diode, Tj=25℃	170	A
Current Squared Time	I^2t	1ms≦t＜10ms Tc=25℃	110	A^2s
Dielectric Strength	Vdis	Terminals to case, AC 1 minute	2.5	kV
Mounting Torque	TOR	(Recommended torque : 0.5N･m)	0.8	N･m

●Electrical Characteristics (If not specified Tc=25℃)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	I_F=5A, Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	I_R	V_R=V_{RM}, Pulse measurement, Rating of per diode	Max.10	μA
Thermal Resistance	θ jc	junction to case With heatsink	Max.1.9	℃/W
	θ jl	junction to lead Without heatsink	Max.6	
	θ ja	junction to ambient Without heatsink	Max.26	

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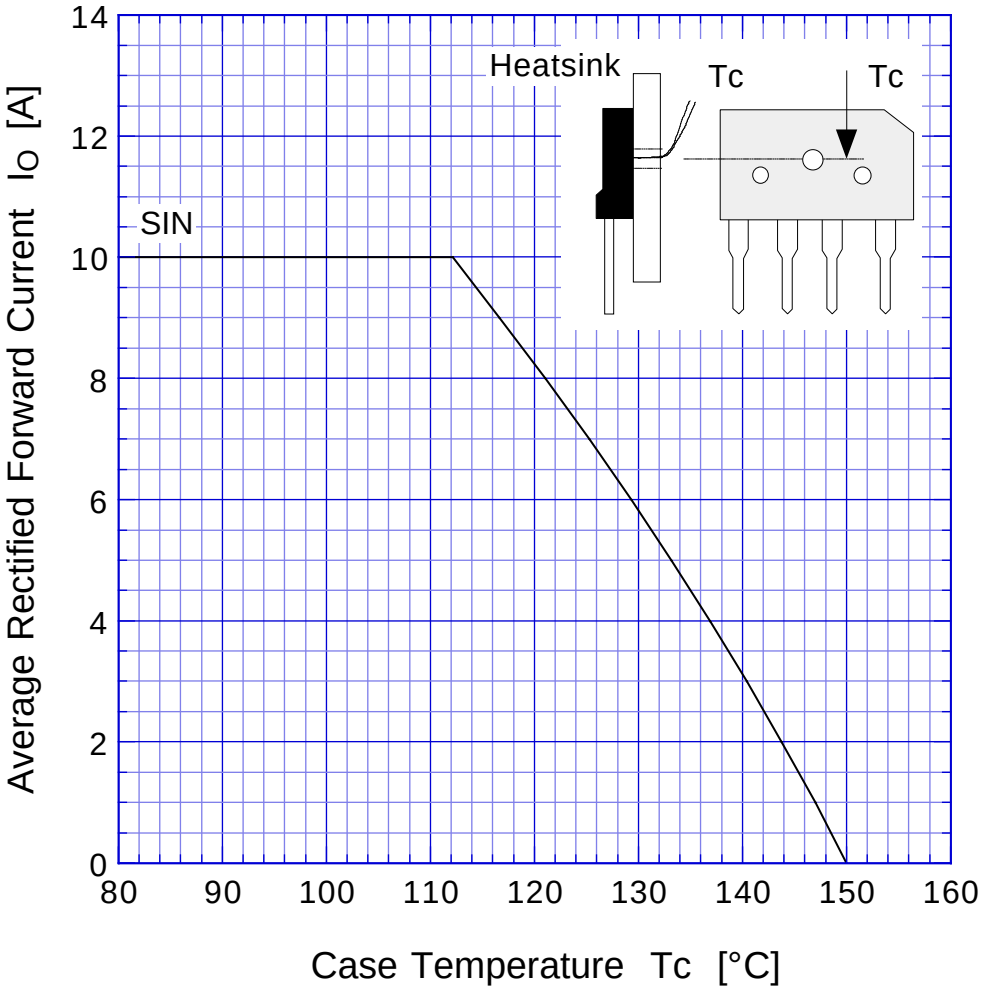
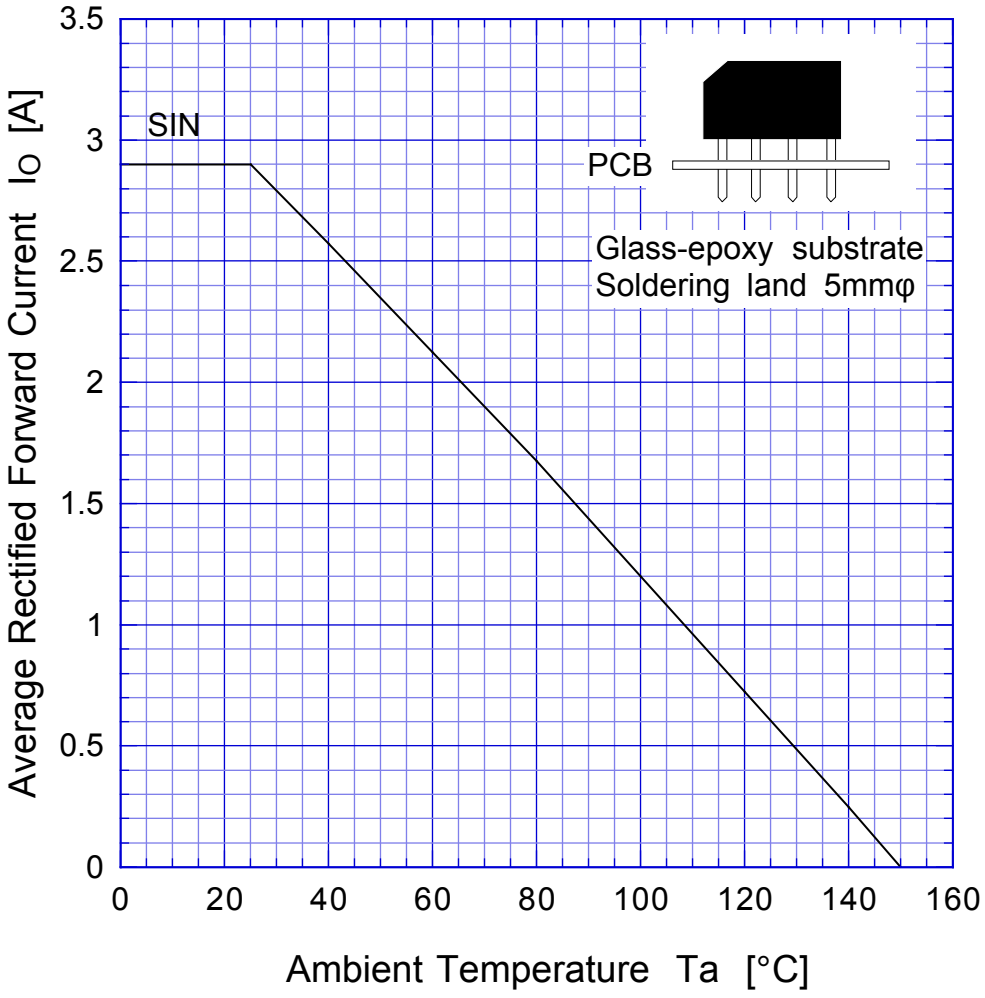
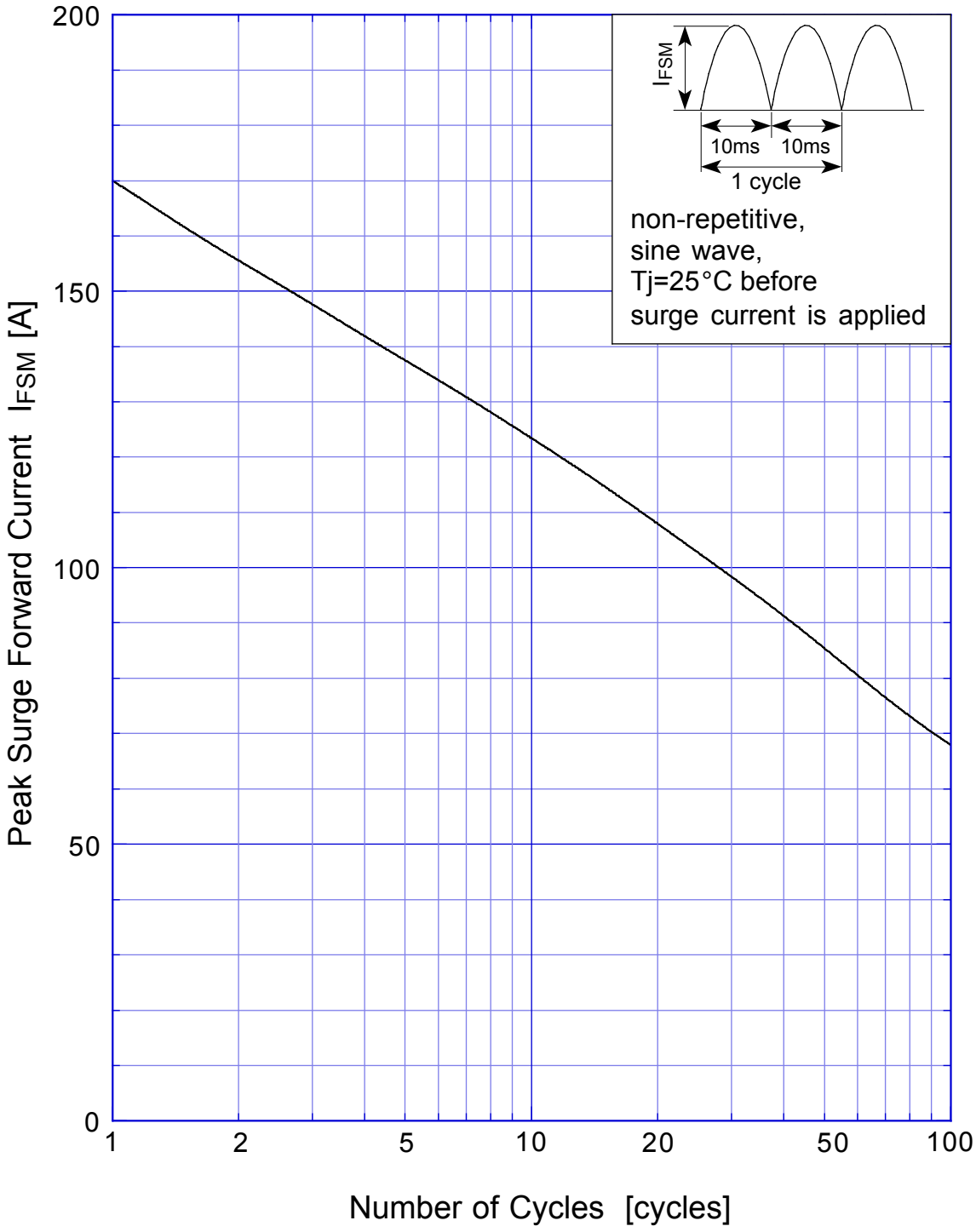
D10XBxH Derating Curve



Sine wave
R-load
with heatsink

D10XBxH Derating Curve



Sine wave
R-load
Free in air

D10XBxH Peak Surge Forward Capability